Vertical Cavity Surface **Emitting Laser in TO-46** Package



OPV215, OPV215Y

Features

- Attenuated Optics
- 850 nm VCSEL technology
- High thermal stability
- Up to 1.25 Gbps
- Recommended for multimode fiber applications •
- Microbead lens
- Pin out and attenuation options available on request
- Burned in for communication level reliability
- High optical coupling to MM fiber

Description

The OPV215 is a high performance 850nm VCSEL packaged for high speed communication links. OPV215 combines all the performance advantages of a VCSEL with the addition of a power monitor diode for precise control of optical power and about 30% optical attenuation for noise suppression.

The OPV215Y is identical electrically and optically and differs only in pin out. Refer to mechanical drawings for details.

This product's combination of features including high speed, high output power and concentric beam make it an ideal transmitter for integration into all types of data communications equipment.

Applications include:

- Fibre Channel
- **Gigabit Ethernet**
- ATM
- VSR (Very Short Reach)
- Intra-system links
- Optical backplane interconnects.

Absolute Maximum Ratings (T_A = 25°C unless otherwise noted)

Technical Data

Absolute Maximum Ratings (T _A = 25° C unless otherwise noted)							
	Maximum Reverse Voltage	5 Volts					
	Storage Temperature	-40 to +125℃					
	Operating Temperature	-40 to +85° C					
	Soldering Lead Temperature	260°C for 10 Seconds					
	Max. Continuous Optical Power at 70℃	0.8 mW					



Additional laser safety information can be found on the Optek website. See application #221. Classification is not marked on the device due to space limitations. See package outline for centerline of optical radiance. Operating devices beyond maximum rating may cause devices to exceed rated classification

OPV215, OPV215Y Technical Data



SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS	TEST CONDITION
P _{OT}	Power Out Total	0.7		3.0	mW	I _F = 12 mA
I _{TH}	Threshold Current	2.0		5.5	mA	Note 1
V_{F}	Forward Voltage			2.15	V	I _F = 12 mA
I _R	Reverse Current			30	nA	$V_R = 5 V$
R _s	Series Resistance	14		40	ohms	Note 2
η	Slope Efficiency	0.10			mW/mA	Note 3
I _{RPD}	Reverse Current, photo diode			30	nA	$V_R = 5 V$
	Linearity	0.0			-	Note 4
I _M	Monitor Current	20		30 30	μΑ	$I_{\rm F} = 12 \text{ mA}, V_{\rm R} = 5 \text{ V}$
λ	Wavelength	830	3	860	nm	
Δλ	Optical Bandwidth		L.	0.85	nm	
t _r ,t _f	Rise and Fall Time		200		ps	20% to 80%
N _{RI}	Relative Intensity Noise		-123		dB/Hz	
$\Delta\eta/\Delta T$	Temp Coefficient of Slope Efficiency		-40		%/°C	(0°-70°C)
$\Delta\lambda/\Delta T$	Temp Coefficient of Wavelength		0.06		nm/℃	0°-70°C
$\Delta I_{TH} / \Delta T$	Temp Coefficient of Threshold Current		± 1.5		mA	0°-70°C
$\Delta V_{F} / \Delta T$	Temperature Coefficient for VF		-2.5		mV/℃	

Electrical/Optical Characteristics (at 25 °C unless otherwise specified)

NOTES:

(1) Threshold Current is based on the two line intersection method specified in Telcordia GR-468-Core. Line 1 from 6 mA to 8 mA. Line 2 from 0 mA to 2 mA.

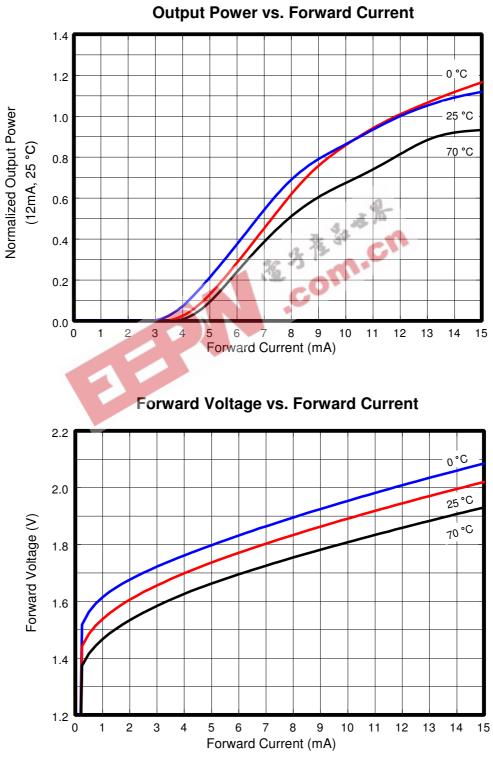
(2) Series Resistance is the slope of the Voltage-Current line from 8 to 12 mA.

(3) Slope efficiency, is the slope of the best fit LI line from 8 mA to 12 mA using no larger than .5 mA test interval points.

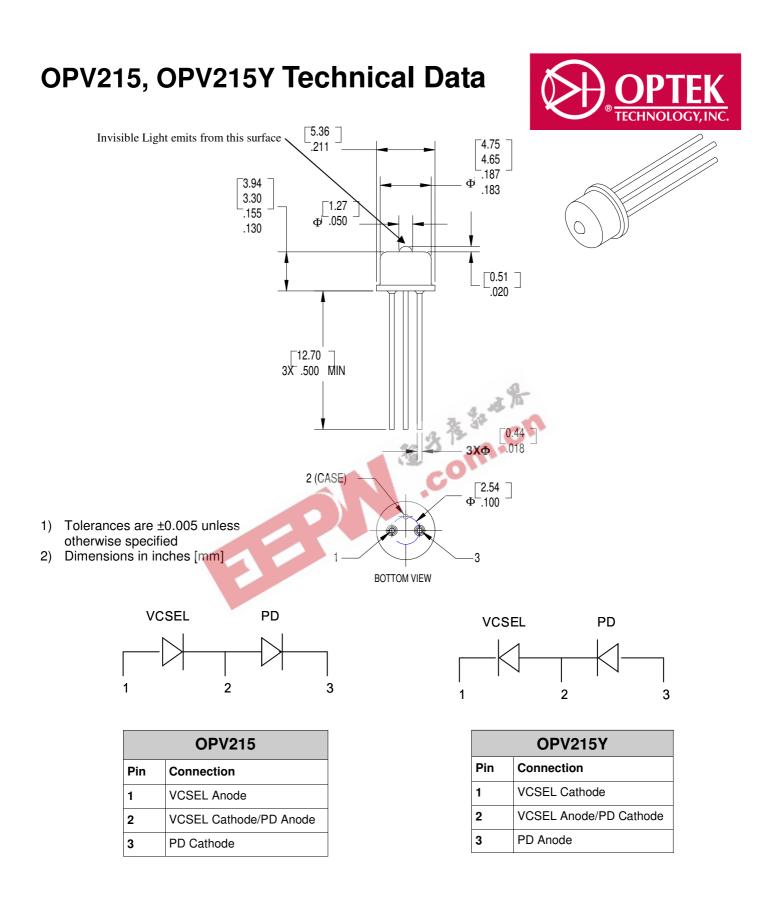
(4) Using data points taken from slope efficiency, delta L/ delta I is calculated for each adjacent pair of 0.5mA points. The minimum is 0.0 (no negative values allowed)



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Optek reserves the right to	Issue 3.2			
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Optek reserves the right to make changes at any time in order to improve design and to supply the best product possible.	Issue 3.2

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